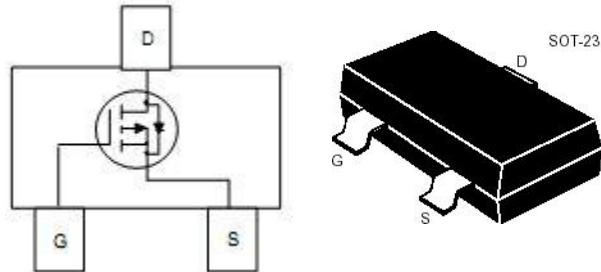


FS3401M

SOT-23 場效應晶體管(SOT-23 Field Effect Transistors)



P-Channel Enhancement-Mode MOS FETs

P 沟道增强型 MOS 场效应管

■MAXIMUM RATINGS 最大額定值

| Characteristic 特性參數 | Symbol 符號 | Max 最大值 | Unit 單位 |
|---|--------------|-------------|------------|
| Drain-Source Voltage 漏極-源極電壓 | BV_{DSS} | -30 | V |
| Gate- Source Voltage 柵極-源極電壓 | V_{GS} | ± 12 | V |
| Drain Current (continuous) 漏極電流-連續 | I_D | -4.1 | A |
| Drain Current (pulsed) 漏極電流-脈沖 | I_{DM} | -18 | A |
| Total Device Dissipation 總耗散功率 TA=25°C 環境溫度為 25°C | P_D | 1400 | mW |
| Junction 結溫 | T_J | 150 | °C |
| Storage Temperature 儲存溫度 | T_{stg} | -55 to +150 | °C |

■DEVICE MARKING 打標

FS3401M=A19T

FS3401M

■ ELECTRICAL CHARACTERISTICS 電特性

($T_A=25^\circ\text{C}$ unless otherwise noted 如無特殊說明，溫度為 25°C)

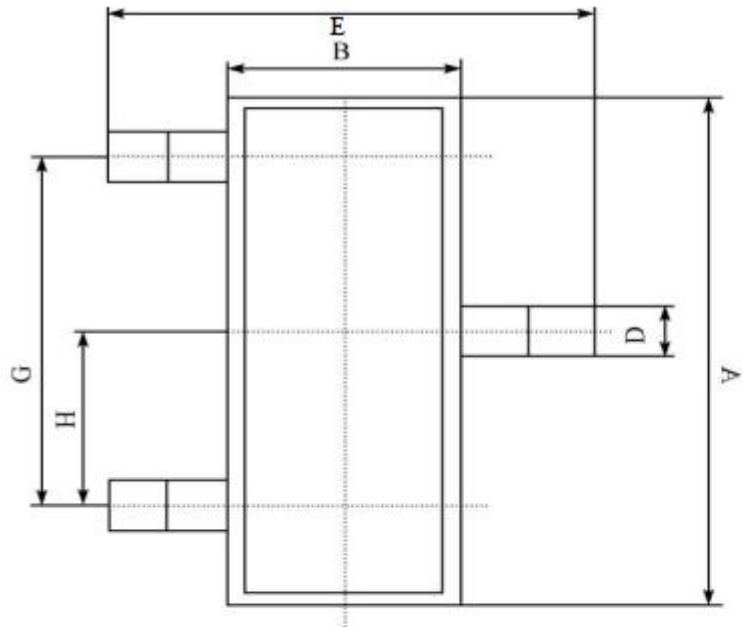
| Characteristic 特性參數 | Symbol 符號 | Min 最小值 | Typ 典型值 | Max 最大值 | Unit 單位 |
|--|---------------------|------------|------------|------------|------------------|
| Drain-Source Breakdown Voltage 漏極-源極擊穿電壓($I_D = -250\mu\text{A}, V_{GS} = 0\text{V}$) | BV_{DSS} | -30 | — | — | V |
| Gate Threshold Voltage 柵極開啟電壓($I_D = -250\mu\text{A}, V_{GS} = V_{DS}$) | $V_{GS(\text{th})}$ | -0.6 | — | -2 | V |
| Diode Forward Voltage Drop 內附二極管正向壓降($I_S = -1\text{A}, V_{GS} = 0\text{V}$) | V_{SD} | — | — | -1 | V |
| Zero Gate Voltage Drain Current 零柵壓漏極電流($V_{GS} = 0\text{V}, V_{DS} = -24\text{V}$) ($V_{GS} = 0\text{V}, V_{DS} = -24\text{V}, T_A = 55^\circ\text{C}$) | I_{DSS} | — | — | -1 -5 | μA |
| Gate Body Leakage 柵極漏電流($V_{GS} = \pm 12\text{V}, V_{DS} = 0\text{V}$) | I_{GSS} | — | — | ± 100 | nA |
| Static Drain-Source On-State Resistance 靜態漏源導通電阻($I_D = -4.2\text{A}, V_{GS} = -10\text{V}$) | $R_{DS(\text{ON})}$ | — | 42 | 50 | $\text{m}\Omega$ |
| Static Drain-Source On-State Resistance 靜態漏源導通電阻($I_D = -2\text{A}, V_{GS} = -4.5\text{V}$) | $R_{DS(\text{ON})}$ | — | 53 | 60 | $\text{m}\Omega$ |
| Static Drain-Source On-State Resistance 靜態漏源導通電阻($I_D = -1\text{A}, V_{GS} = -2.5\text{V}$) | $R_{DS(\text{ON})}$ | — | 80 | 85 | $\text{m}\Omega$ |
| Input Capacitance 輸入電容 ($V_{GS} = 0\text{V}, V_{DS} = -15\text{V}, f = 1\text{MHz}$) | C_{ISS} | — | 954 | — | pF |
| Output Capacitance 輸出電容 ($V_{GS} = 0\text{V}, V_{DS} = -15\text{V}, f = 1\text{MHz}$) | C_{OSS} | — | 115 | — | pF |
| Turn-ON Time 开启時間 ($V_{DS} = -15\text{V}, V_{GS} = -10\text{V}, R_{GEN} = 6\Omega$) | $t_{(\text{on})}$ | — | 6 | — | ns |
| Turn-OFF Time 关斷時間 ($V_{DS} = -15\text{V}, V_{GS} = -10\text{V}, R_{GEN} = 6\Omega$) | $t_{(\text{off})}$ | — | 38 | — | ns |

Pulse Width $\leq 300\ \mu\text{s}$; Duty Cycle $\leq 2.0\%$

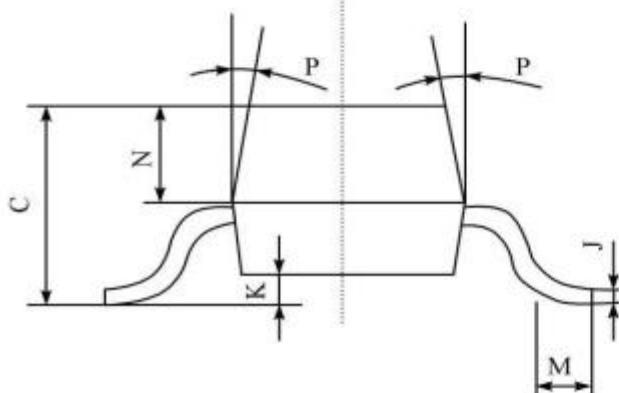
FS3401M

■DIMENSION 外形封裝尺寸

單位(UNIT): mm



| 代碼 | 範圍(單位:mm) |
|----|-------------------------|
| A | 2.80~3.00 |
| B | 1.20~1.40 |
| C | 0.90~1.10 |
| D | 0.30~0.50 |
| E | 2.20~2.60 |
| G | 1.80~2.00 |
| H | 0.90~1.00 |
| J | 0.08~0.18 |
| K | 0.02~0.12 |
| M | ≥ 0.22 |
| N | 0.50~0.70 |
| P | $6^\circ \sim 10^\circ$ |



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